# 1 Electrònica

### 1.1 Díodes

$$\begin{array}{c} V_p - V_n \geq V_\gamma \implies \operatorname{PD} \\ & \operatorname{no} \operatorname{PD} \implies \operatorname{PI} \\ & \operatorname{PD} \implies I \neq 0 \\ & \operatorname{PI} \implies I = 0 \\ & P_{cons} = \Delta VI \\ \end{array}$$
PI i  $\Delta V_{Z\text{co}} \geq V_Z \implies \operatorname{regi\'o} \operatorname{Zener}$ 

### 1.2 NMOS

$$\begin{split} V_{GS} &= V_G - V_S & V_{DS} = V_D - V_S \\ V_{GS} &\leq V_T \implies \text{Tall (OFF)} \implies I_D = 0 \\ V_{GS} &> V_T \implies \text{Canal (ON)} \implies I_D \neq 0 \\ V_{DS} &< V_{GS} - V_T \implies \text{Regi\'o \`ohmica} \\ V_{DS} &< V_{GS} - V_T \iff V_{GD} > V_T \\ V_{DS} &> V_{GS} - V_T \iff V_{GD} < V_T \implies \text{Regi\'o \'de saturaci\'o} \\ V_{DS} &> V_{GS} - V_T \iff V_{GD} < V_T \end{split}$$

## 1.3 **PMOS**

$$V_{GS} \geq V_T \implies \text{Tall (OFF)}$$
 
$$V_{GS} < V_T \implies \text{Canal (ON)}$$
 
$$V_{DS} > V_{GS} - V_T \implies \text{Regi\'o \`omica}$$
 
$$V_{DS} < V_{GS} - V_T \implies \text{Regi\'o \'de saturaci\'o}$$

# 2 Ones